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CP-2818

First Named Inventor	Christopher S. Johnson	TRANSMITTAL FORM UNDER 37 CFR 1.10 (LARGE ENTITY)
Serial No.	10/073,543	
Filing Date	February 11, 2002	
Group Art Unit	2818	
Examiner Name	Thong Quoc Le	
Confirmation No.	5205	
Attorney Docket No.	400.149US01	
Title: USER SELECTABLE BANK FOR DRAM		

Mail Stop: Non-Fee Amendment
Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

Enclosures**The following documents are enclosed:**

- ☒ An amendment and response to Office Action of May 19, 2003 (7 pgs.);
☒ A return postcard.

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(LARGE ENTITY TRANSMITTAL UNDER 37 C.F.R. 1.10)



S/N 10/073,543

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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AMENDMENT AND RESPONSE

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In response to the Office Action dated May 19, 2003, please amend the above-identified patent application as follows:

IN THE CLAIMS

1. (Original) A memory device comprising:
an array of memory cells arranged in a plurality of addressable banks, each bank comprises addressable rows and columns of memory cells;
a mode register; and
address circuitry coupled to the mode register to configure the addressable banks in response to a program state of the mode register.
2. (Original) The memory device of claim 1 wherein the addressable banks can be configured as either four or eight banks.
3. (Original) The memory device of claim 1 wherein the address circuitry selectively routes address signal to either a row decoder or a bank decoder in response to the mode register.
4. (Original) A dynamic random access memory comprising:
an array of X memory cells;